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ON Semiconductor ASM3I2579AF-06OR

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ASM3P2579A

Peak EMI Reducing Solution

Features

- Generates an EMI optimized clock signal at the output.
- Integrated loop filter components.
- Operates with a 3.3 / 2.5V Supply.
- Operating current less than 4mA.
- · CMOS design.
- Input frequency range: 12MHz to 30MHz for 2.5V
 12MHz to 30MHz for 3.3V
- Generates a 1X low EMI spread spectrum clock of the input frequency.
- Spread Spectrum Enable Control.
- Frequency deviation: ±1% @ 24MHz
- Available in 6L-TSOP (6L-TSOT-23).

Product Description

The ASM3P2579A is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The ASM3P2579A reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of all clock dependent signals. The ASM3P2579A allows significant system cost savings by reducing the number of circuit board layers, ferrite beads and shielding that are traditionally required to pass EMI regulations.

-The ASM3P2579A uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all digital method.

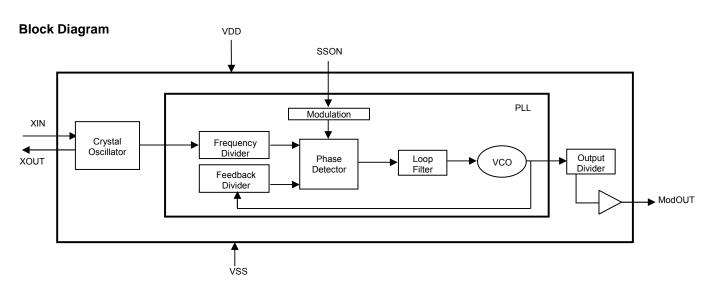
The ASM3P2579A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This result in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation.'

Applications

The ASM3P2579A is targeted towards all portable devices like MP3 players and digital still cameras.

Key Specifications

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Description	Specification
Supply voltages	VDD = 3.3V/2.5V
Cycle-to-Cycle Jitter	±200pS (Typ)
Output Duty Cycle	45/55% (worst case)
Modulation Rate Equation	F _{IN} /640
Frequency Deviation	±1% @ 24MHz



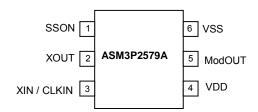


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Pin Configuration (6L-TSOP)



Pin Description

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Pin#	Pin Name	Туре	Description		
1	SSON	I	When SSON is HIGH, the spread spectrum is enabled and when LOW, it turns off the spread spectrum. Connect the pin to ground when Spread Spectrum feature is not required.		
2	XOUT	0	Crystal connection. If using an external reference, this pin must be left unconnected.		
3	XIN / CLKIN	I	Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock.		
4	VDD	Р	Power supply for the entire chip.		
5	ModOUT	0	Spread spectrum clock output.		
6	VSS	Р	Ground connection.		

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
VDD, V _{IN}	Voltage on any pin with respect to Ground	-0.5 to +4.6	V
T _{STG}	Storage temperature	-65 to +125	C
Ts	Max. Soldering Temperature (10 sec)	260	c
T_J	Junction Temperature	150	${\mathfrak C}$
T_DV	Static Discharge Voltage (As per JEDEC STD22- A114-B)	2	KV

Operating Conditions

Parameter	Description	Min	Max	Unit
VDD	Supply Voltage	2.375	3.6	V
T _A	Operating Temperature (Ambient Temperature)	-40	+85	င
C_L	Load Capacitance		15	pF
C _{IN}	Input Capacitance		7	pF

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DC Electrical Characteristics for 2.5V Supply

Symbol	Parameter	Min	Тур	Max	Unit
V _{IL}	Input low voltage	VSS-0.3		0.8	V
V _{IH}	Input high voltage	2.0		VDD+0.3	V
I _{IL}	Input low current			-35	μA
I _{IH}	Input high current			35	μA
I _{XOL}	XOUT output low current (@ 0.5V, VDD = 2.5V)		3		mA
I _{XOH}	XOUT output high current (@ 1.8V, VDD = 2.5V)		3		mA
V _{OL}	Output low voltage (VDD = 2.5V, I _{OL} = 8mA)			0.6	V
V _{OH}	Output high voltage (VDD = 2.5V, I _{OH} = 8mA)	1.8			V
I _{DD}	Static supply current ¹		1.1		mA
Icc	Dynamic supply current (2.5V, 24MHz and no load)		3.5		mA
VDD	Operating Voltage	2.375	2.5	2.625	V
t _{ON}	Power-up time (first locked cycle after power-up)			5	mS
Z _{OUT}	Output impedance		50		Ω
Note: 1. XIN	CLKIN is made low.	•		•	

AC Electrical Characteristics for 2.5V Supply

Symbol	Parameter			Тур	Max	Unit
CLKIN	Input frequency		12		30	MHz
ModOUT	Output frequency		12		30	MHz
	Fraguency Deviation	Input Frequency = 12MHz		±1.65		%
f _d	Frequency Deviation Input Frequency	Input Frequency = 30MHz		±0.80		70
t _{LH} ¹	Output rise time (measured from 0.7V to 1.7V)		0.7	1.5	1.9	nS
t _{HL} 1	Output fall time (measured from 1.7V to 0.7V)		0.4	1.0	1.1	nS
t _{JC}	Jitter (cycle-to-cycle)			±200		pS
t _D	Output duty cycle		45	50	55	%
Note: 1. t _{LH} and	t _{HL} are measured into a capacitive load of	15pF.				



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DC Electrical Characteristics for 3.3V Supply

Symbol	Parameter	Min	Тур	Max	Unit
V _{IL}	Input low voltage	VSS-0.3		0.8	V
V _{IH}	Input high voltage	2.0		VDD+0.3	V
I _{IL}	Input low current			-35	μA
I _{IH}	Input high current			35	μΑ
I _{XOL}	XOUT output low current (@ 0.4V, VDD = 3.3V)		3		mA
I _{XOH}	XOUT output high current (@ 2.5V, VDD = 3.3V)		3		mA
V _{OL}	Output low voltage (VDD = 3.3V, I _{OL} = 8mA)			0.4	V
V _{OH}	Output high voltage (VDD = 3.3V, I _{OH} = 8mA)	2.5			V
I _{DD}	Static supply current ¹		1.2		mA
Icc	Dynamic supply current (3.3V, 24MHz and no load)		4.0		mA
VDD	Operating Voltage	2.7	3.3	3.6	V
t _{ON}	Power-up time (first locked cycle after power-up)			5	mS
Z _{OUT}	Output impedance		45		Ω
Note: 1. XIN	CLKIN is made low.	•		•	•

AC Electrical Characteristics for 3.3V Supply

Symbol	Parameter			Тур	Max	Unit
CLKIN	Input frequency		12		30	MHz
ModOUT	Output frequency		12		30	MHz
f	Frequency Doviction	Input Frequency = 12MHz		±1.65		%
f _d Frequency Deviation		Input Frequency = 30MHz		±0.80		70
t _{LH} ¹	Output rise time (measured from 0.8 to 2.0V)		0.5	1.4	1.7	nS
t _{HL} 1	Output fall time (measured at 2.0V to 0.8V)		0.4	1.0	1.2	nS
t _{JC}	Jitter (cycle-to-cycle)			±200		pS
t _D	Output duty cycle		45	50	55	%
Note: 1. t _{LH} and	t _{HL} are measured into a capacitive load of 15pF.					



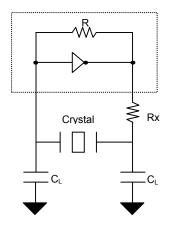
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Typical Crystal Specifications

Fundamental AT cut parallel resonant crystal				
Nominal frequency	14.31818MHz			
Frequency tolerance	± 50 ppm or better at 25℃			
Operating temperature range	-25℃ to +85℃			
Storage temperature	-40℃ to +85℃			
Load capacitance(C _P)	18pF			
Shunt capacitance	7pF maximum			
ESR	25 Ω			

Note: Note: C_L is Load Capacitance and Rx is used to prevent oscillations at overtone frequency of the Fundamental frequency.

Typical Crystal Interface Circuit

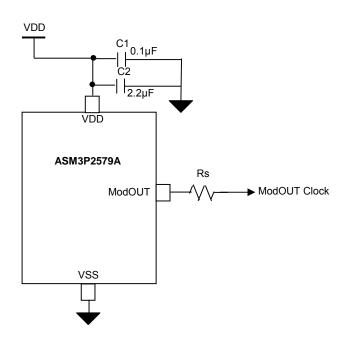


 $C_L = 2*(C_P - C_S),$

Where C_P = Load capacitance of crystal

 C_S = Stray capacitance due to C_{IN} , PCB, Trace etc.

Typical Application Schematic



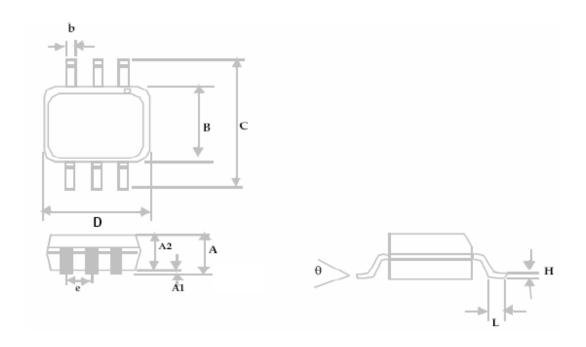
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Package Information

6L-TSOP



	Dimensions				
Symbol	Inches		Millim	neters	
	Min	Max	Min	Max	
Α		0.04		1.00	
A1	0.00	0.004	0.00	0.10	
A2	0.033	0.036	0.84	0.90	
b	0.012	0.02	0.30	0.50	
Н	0.005	BSC	0.127 BSC		
D	0.114	BSC	2.90	BSC	
В	0.06 BSC		1.60	BSC	
е	0.0374 BSC		0.950	BSC	
С	0.11 BSC		2.80	BSC	
L	0.0118	0.02	0.30	0.50	
θ	0°	4°	0°	4°	



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Ordering Information

Part Number	Marking	Package Type	Temperature
ASM3I2579AF-06OR	S5L	6L-TSOP (6L-TSOT-23), TAPE & REEL, Pb Free	-40℃ to +85℃

A "microdot" placed at the end of last row of marking or just below the last row toward the center of package indicates Pb-free.

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